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Kind regards,

Team Nexperia

# 74CBTLV16211

24-bit bus switch
Rev. 7 — 9 November 2016

Product data sheet

#### **General description** 1.

The 74CBTLV16211 provides a dual 12-bit high-speed bus switch with separate output enable inputs (10E, 20E). The low on-state resistance of the switch allows connections to be made with minimal propagation delay. The switch is disabled (high-impedance OFF-state) when the output enable (nOE) input is HIGH.

To ensure the high-impedance OFF-state during power-up or power-down, 1OE and 2OE should be tied to the V<sub>CC</sub> through a pull-up resistor. The minimum value of the resistor is determined by the current-sinking capability of the driver.

Schmitt trigger action at control input makes the circuit tolerant to slower input rise and fall times across the entire V<sub>CC</sub> range from 2.3 V to 3.6 V.

This device is fully specified for partial power-down applications using I<sub>OFF</sub>. The I<sub>OFF</sub> circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

#### Features and benefits 2.

- Supply voltage range from 2.3 V to 3.6 V
- High noise immunity
- Complies with JEDEC standard:
  - ◆ JESD8-5 (2.3 V to 2.7 V)
  - ◆ JESD8-B/JESD36 (2.7 V to 3.6 V)
- ESD protection:
  - HBM JESD22-A114F exceeds 2000 V
  - MM JESD22-A115-A exceeds 200 V
  - ◆ CDM AEC-Q100-011 revision B exceeds 1000 V
- $\blacksquare$  5  $\Omega$  switch connection between two ports
- Rail to rail switching on data I/O ports
- CMOS low power consumption
- Latch-up performance exceeds 250 mA per JESD78B Class I level A
- I<sub>OFF</sub> circuitry provides partial Power-down mode operation
- TSSOP56 packages: SOT364-1 and SOT481-2
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

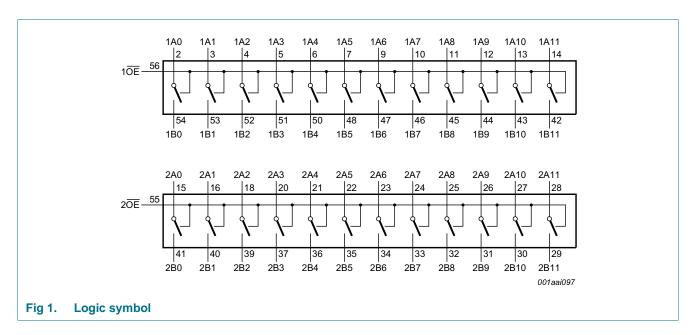


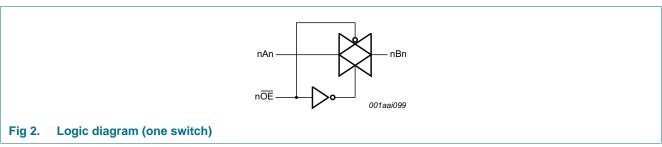
## 3. Ordering information

Table 1. Ordering information

Type number	Package							
	Temperature range	Name	Description	Version				
74CBTLV16211DGG	–40 °C to +125 °C	TSSOP56	plastic thin shrink small outline package; 56 leads; body width 6.1 mm	SOT364-1				
74CBTLV16211DGV	–40 °C to +125 °C	TSSOP56	plastic thin shrink small outline package; 56 leads; body width 4.4 mm	SOT481-2				

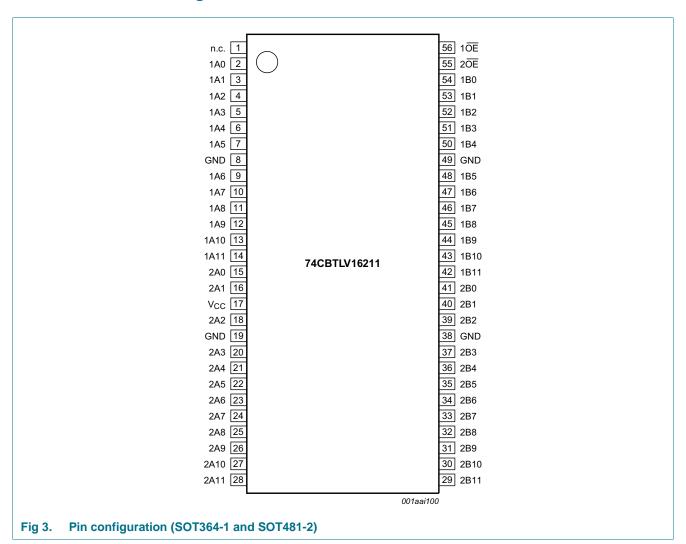
# 4. Functional diagram





## 5. Pinning information

### 5.1 Pinning



### 5.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
n.c.	1	not connected
1A0 to 1A11	2, 3, 4, 5, 6, 7, 9, 10, 11, 12, 13, 14	independent input or output
2A0 to 2A11	15, 16, 18, 20, 21, 22, 23, 24, 25, 26, 27, 28	independent input or output
GND	8, 19, 38, 49	ground (0 V)
V <sub>CC</sub>	17	supply voltage
2B0 to 2B11	41, 40, 39, 37, 36, 35, 34, 33, 32, 31, 30, 29	independent input or output

Table 2. Pin description ... continued

Symbol	Pin	Description
	54, 53, 52, 51, 50, 48, 47, 46, 45, 44, 43, 42	independent input or output
2 <del>OE</del>	55	output enable input (active-LOW)
1 <del>OE</del>	56	output enable input (active-LOW)

## 6. Functional description

#### Table 3. Function table [1]

Output enable input OE	Function switch
L	ON-state ON-state
Н	OFF-state

<sup>[1]</sup> H = HIGH voltage level; L = LOW voltage level.

### 7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		-0.5	+4.6	V
VI	input voltage	[1]	-0.5	+4.6	V
V <sub>SW</sub>	switch voltage	enable and disable mode [1]	-0.5	V <sub>CC</sub> + 0.5	V
I <sub>IK</sub>	input clamping current	V <sub>I</sub> < -0.5 V	-50	-	mA
I <sub>SK</sub>	switch clamping current	V <sub>I</sub> < -0.5 V	-50	-	mA
I <sub>SW</sub>	switch current	$V_{SW} = 0 V \text{ to } V_{CC}$	-	±128	mA
I <sub>CC</sub>	supply current		-	+100	mA
I <sub>GND</sub>	ground current		-100	-	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation	$T_{amb} = -40  ^{\circ}\text{C} \text{ to } +125  ^{\circ}\text{C}$	-	600	mW

<sup>[1]</sup> The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.

## 8. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		2.3	3.6	V
VI	input voltage		0	3.6	V
V <sub>SW</sub>	switch voltage	enable and disable mode	0	V <sub>CC</sub>	V
T <sub>amb</sub>	ambient temperature		-40	+125	°C
Δt/ΔV	input transition rise and fall rate	V <sub>CC</sub> = 2.3 V to 3.6 V	0	200	ns/V

<sup>[1]</sup> Applies to control signal levels.

74CBTLV16211

<sup>[2]</sup> For TSSOP56 packages: above 55 °C the value of Ptot derates linearly with 8.0 mW/K.

### 9. Static characteristics

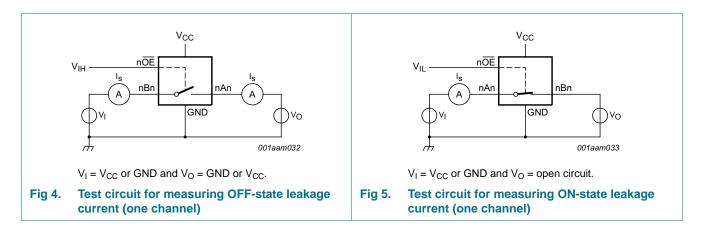
Table 6. Static characteristics

At recommended operating conditions voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	T <sub>amb</sub> =	–40 °C to	+85 °C	T <sub>amb</sub> = -40 °	C to +125 °C	Unit
			Min	Typ[1]	Max	Min	Max	
V <sub>IH</sub>	HIGH-level	V <sub>CC</sub> = 2.3 V to 2.7 V	1.7	-	-	1.7	-	V
	input voltage	V <sub>CC</sub> = 3.0 V to 3.6 V	2.0	-	-	2.0	-	V
$V_{IL}$	LOW-level input	V <sub>CC</sub> = 2.3 V to 2.7 V	-	-	0.7	-	0.7	V
	voltage	V <sub>CC</sub> = 3.0 V to 3.6 V	-	-	0.9	-	0.9	V
II	input leakage current	pin n $\overline{OE}$ ; V <sub>I</sub> = GND to V <sub>CC</sub> ; V <sub>CC</sub> = 3.6 V	-	-	±1.0	-	±20	μА
I <sub>S(OFF)</sub>	OFF-state leakage current	V <sub>CC</sub> = 3.6 V; see <u>Figure 4</u>	-	-	±1	-	±20	μА
I <sub>S(ON)</sub>	ON-state leakage current	V <sub>CC</sub> = 3.6 V; see <u>Figure 5</u>	-	-	±1	-	±20	μА
I <sub>OFF</sub>	power-off leakage current	$V_1 \text{ or } V_O = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V}$	-	-	±10	-	±50	μА
I <sub>CC</sub>	supply current	$V_I = GND \text{ or } V_{CC}; I_O = 0 \text{ A};$ $V_{SW} = GND \text{ or } V_{CC};$ $V_{CC} = 3.6 \text{ V}$	-	-	10	-	50	μА
Δl <sub>CC</sub>	additional supply current	$\begin{aligned} &\text{pin n}\overline{\text{OE}}; \ V_{\text{I}} = V_{\text{CC}} - 0.6 \ \text{V}; \\ &V_{\text{SW}} = \text{GND or } V_{\text{CC}}; \\ &V_{\text{CC}} = 3.6 \ \text{V} \end{aligned} $	-	-	300	-	2000	μΑ
Cı	input capacitance	pin n $\overline{OE}$ ; V <sub>CC</sub> = 3.3 V; V <sub>I</sub> = 0 V to 3.3 V	-	0.9	-	-	-	pF
C <sub>S(OFF)</sub>	OFF-state capacitance	$V_{CC} = 3.3 \text{ V}; V_1 = 0 \text{ V to } 3.3 \text{ V}$	-	5.2	-	-	-	pF
C <sub>S(ON)</sub>	ON-state capacitance	$V_{CC} = 3.3 \text{ V}; V_{I} = 0 \text{ V to } 3.3 \text{ V}$	-	14.3	-	-	-	pF

- [1] All typical values are measured at  $T_{amb} = 25$  °C.
- [2] One input at 3 V, other inputs at  $V_{CC}$  or GND.

#### 9.1 Test circuits



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#### 9.2 ON resistance

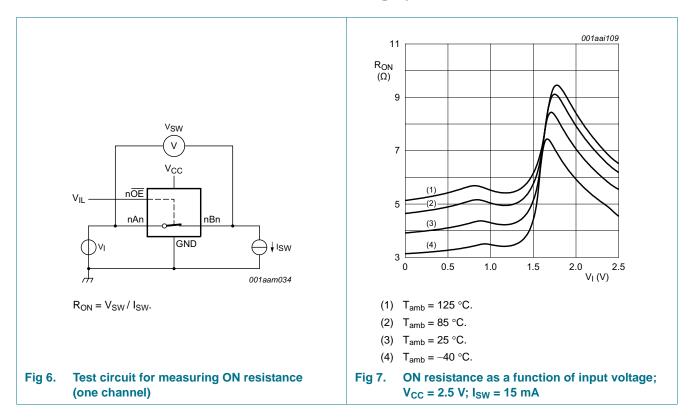
Table 7. Resistance R<sub>ON</sub>

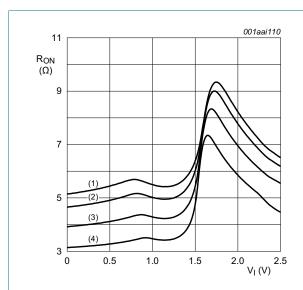
At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for test circuit see Figure 6.

Symbol	Parameter	Conditions		T <sub>amb</sub> =	–40 °C to	+85 °C	T <sub>amb</sub> = -40 °C	Unit	
				Min	Typ[1]	Max	Min	Max	
R <sub>ON</sub>	ON resistance	V <sub>CC</sub> = 2.3 V to 2.7 V; see <u>Figure 7</u> to <u>Figure 9</u>	[2]						
		$I_{SW} = 64 \text{ mA}; V_I = 0 \text{ V}$		-	4.2	8.0	-	15.0	Ω
		$I_{SW} = 24 \text{ mA}; V_I = 0 \text{ V}$		-	4.2	8.0	-	15.0	Ω
		$I_{SW} = 15 \text{ mA}; V_I = 1.7 \text{ V}$		-	8.4	40	-	60.0	Ω
		V <sub>CC</sub> = 3.0 V to 3.6 V; see <u>Figure 10</u> to <u>Figure 12</u>							
		$I_{SW} = 64 \text{ mA}; V_I = 0 \text{ V}$		-	4.0	7.0	-	11.0	Ω
		$I_{SW} = 24 \text{ mA}; V_I = 0 \text{ V}$		-	4.0	7.0	-	11.0	Ω
		$I_{SW} = 15 \text{ mA}; V_I = 2.4 \text{ V}$		-	6.2	15	-	25.5	Ω

- [1] Typical values are measured at  $T_{amb}$  = 25 °C and nominal  $V_{CC}$ .
- [2] Measured by the voltage drop between the A and B terminals at the indicated current through the switch. ON-state resistance is determined by the lower of the voltages of the two (A or B) terminals.

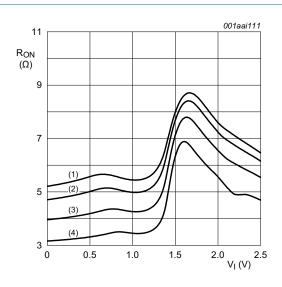
### 9.3 ON resistance test circuit and graphs





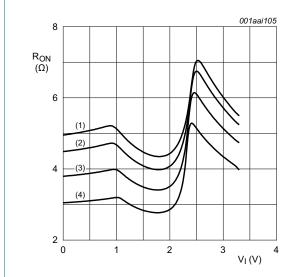
- (1)  $T_{amb} = 125 \, ^{\circ}C$ .
- (2)  $T_{amb} = 85 \, ^{\circ}C$ .
- (3)  $T_{amb} = 25 \, ^{\circ}C$ .
- (4)  $T_{amb} = -40 \, ^{\circ}C$ .

Fig 8. ON resistance as a function of input voltage;  $V_{CC} = 2.5 \text{ V}$ ;  $I_{SW} = 24 \text{ mA}$ 



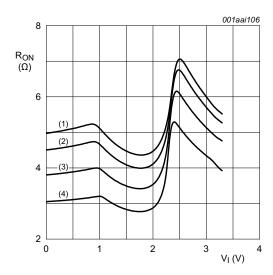
- (1)  $T_{amb} = 125 \, ^{\circ}C$ .
- (2)  $T_{amb} = 85 \, ^{\circ}C$ .
- (3)  $T_{amb} = 25 \, ^{\circ}C$ .
- (4)  $T_{amb} = -40 \, ^{\circ}C$ .

Fig 9. ON resistance as a function of input voltage;  $V_{CC} = 2.5 \text{ V}$ ;  $I_{SW} = 64 \text{ mA}$ 



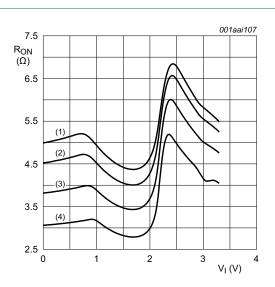
- (1)  $T_{amb} = 125 \, ^{\circ}C$ .
- (2)  $T_{amb} = 85 \, ^{\circ}C$ .
- (3)  $T_{amb} = 25 \, ^{\circ}C$ .
- (4)  $T_{amb} = -40 \, ^{\circ}C$ .

Fig 10. ON resistance as a function of input voltage;  $V_{CC} = 3.3 \text{ V}; I_{SW} = 15 \text{ mA}$ 



- (1)  $T_{amb} = 125 \,^{\circ}C$ .
- (2)  $T_{amb} = 85 \, ^{\circ}C$ .
- (3)  $T_{amb} = 25 \, ^{\circ}C$ .
- (4)  $T_{amb} = -40 \, ^{\circ}C$ .

Fig 11. ON resistance as a function of input voltage;  $V_{CC}$  = 3.3 V;  $I_{SW}$  = 24 mA



- (1)  $T_{amb} = 125 \, ^{\circ}C$ .
- (2)  $T_{amb} = 85 \, ^{\circ}C$ .
- (3)  $T_{amb} = 25 \, ^{\circ}C$ .
- (4)  $T_{amb} = -40 \, ^{\circ}C$ .

Fig 12. ON resistance as a function of input voltage;  $V_{CC} = 3.3 \text{ V}$ ;  $I_{SW} = 64 \text{ mA}$ 

### 10. Dynamic characteristics

**Table 8. Dynamic characteristics** GND = 0 V; for test circuit see Figure 15

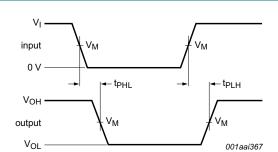
Symbol	Parameter	Conditions	T <sub>amb</sub> =	–40 °C to	+85 °C	T <sub>amb</sub> = -40 °	Unit	
			Min	Typ[1]	Max	Min	Max	
t <sub>pd</sub>	propagation delay	nAn to nBn or nBn to [2][3] nAn; see Figure 13						
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	-	0.13	-	0.2	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	-	-	0.2	-	0.31	ns
t <sub>en</sub>	enable time	nOE to nAn or nBn; [4] see Figure 14						
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.0	2.0	7.0	1.0	7.8	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.0	1.7	6.2	1.0	6.8	ns
t <sub>dis</sub>	disable time	nOE to nAn or nBn; 5 see Figure 14						
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.0	2.6	7.2	1.0	8.1	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.0	3.0	7.7	1.0	8.8	ns

- [1] All typical values are measured at  $T_{amb}$  = 25 °C and at nominal  $V_{CC}$ .
- [2] The propagation delay is the calculated RC time constant of the typical on-state resistance of the switch and the load capacitance, when driven by an ideal voltage source (zero output impedance).
- [3]  $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ .
- [4]  $t_{en}$  is the same as  $t_{PZH}$  and  $t_{PZL}$ .
- [5]  $t_{dis}$  is the same as  $t_{PHZ}$  and  $t_{PLZ}$ .

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### 11. Waveforms



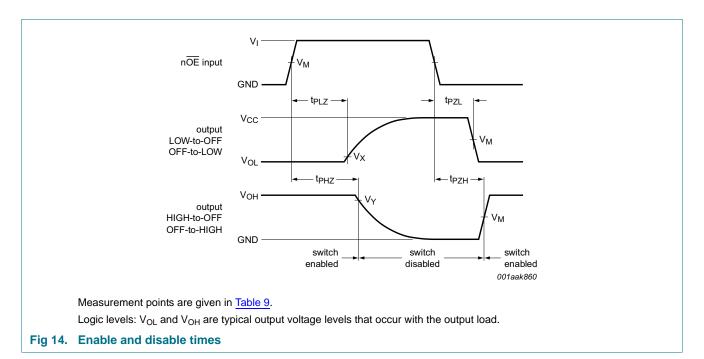
Measurement points are given in Table 9.

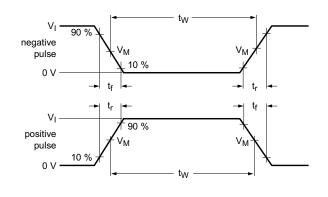
Logic levels:  $V_{OL}$  and  $V_{OH}$  are typical output voltage levels that occur with the output load.

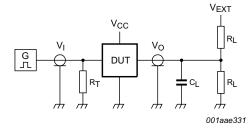
Fig 13. The data input (nAn or nBn) to output (nBn or nAn) propagation delays

Table 9. Measurement points

Supply voltage	Input			Output		
V <sub>CC</sub>	V <sub>M</sub>	V <sub>I</sub>	$t_r = t_f$	V <sub>M</sub>	V <sub>X</sub>	V <sub>Y</sub>
2.3 V to 2.7 V	0.5V <sub>CC</sub>	V <sub>CC</sub>	≤ 2.0 ns	0.5V <sub>CC</sub>	V <sub>OL</sub> + 0.15 V	V <sub>OH</sub> – 0.15 V
3.0 V to 3.6 V	0.5V <sub>CC</sub>	V <sub>CC</sub>	≤ 2.0 ns	0.5V <sub>CC</sub>	V <sub>OL</sub> + 0.3 V	V <sub>OH</sub> – 0.3 V







Test data is given in Table 10.

Definitions for test circuit:

R<sub>L</sub> = Load resistance.

 $C_L$  = Load capacitance including jig and probe capacitance.

 $R_T$  = Termination resistance should be equal to the output impedance  $Z_0$  of the pulse generator.

 $V_{\text{EXT}}$  = External voltage for measuring switching times.

Fig 15. Test circuit for measuring switching times

Table 10. Test data

Supply voltage	Load		V <sub>EXT</sub>		
V <sub>CC</sub>	C <sub>L</sub>	R <sub>L</sub>	t <sub>PLH</sub> , t <sub>PHL</sub>	t <sub>PZH</sub> , t <sub>PHZ</sub>	t <sub>PZL</sub> , t <sub>PLZ</sub>
2.3 V to 2.7 V	30 pF	500 Ω	open	GND	2V <sub>CC</sub>
3.0 V to 3.6 V	50 pF	500 Ω	open	GND	2V <sub>CC</sub>

### 11.1 Additional dynamic characteristics

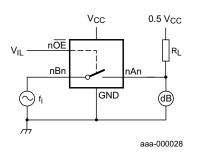
#### Table 11. Additional dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V);  $V_I = GND$  or  $V_{CC}$  (unless otherwise specified);  $t_r = t_f \le 2.5$  ns.

Symbol	Parameter	Conditions	Т	<sub>amb</sub> = 25 °0	•	Unit
			Min	Тур	Max	
f <sub>(-3dB)</sub>	-3 dB frequency response	$V_{CC} = 3.3 \text{ V}; R_L = 50 \Omega; \text{ see } \frac{\text{Figure 16}}{}$	-	458	-	MHz

[1]  $f_i$  is biased at  $0.5V_{CC}$ .

#### 11.2 Test circuits



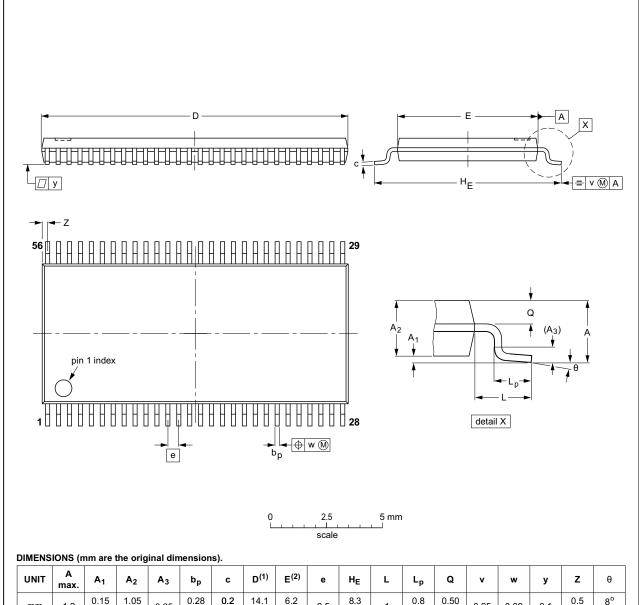
nOE connected to GND; Adjust f<sub>i</sub> voltage to obtain 0 dBm level at output. Increase f<sub>i</sub> frequency until dB meter reads –3 dB.

Fig 16. Test circuit for measuring the frequency response when channel is in ON-state

## 12. Package outline

TSSOP56: plastic thin shrink small outline package; 56 leads; body width 6.1 mm

SOT364-1



UNIT	A max.	A <sub>1</sub>	A <sub>2</sub>	<b>A</b> <sub>3</sub>	bp	С	D <sup>(1)</sup>	E <sup>(2)</sup>	е	HE	L	Lp	Q	v	w	у	Z	θ
mm	1.2	0.15 0.05	1.05 0.85	0.25	0.28 0.17	0.2 0.1	14.1 13.9	6.2 6.0	0.5	8.3 7.9	1	0.8 0.4	0.50 0.35	0.25	0.08	0.1	0.5 0.1	8° 0°

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

	EUROPEAN	ISSUE DATE		
EC JEDEC	JEITA		PROJECTION	ISSUE DATE
MO-153				<del>99-12-27</del> 03-02-19
				EC JEDEC JEHA

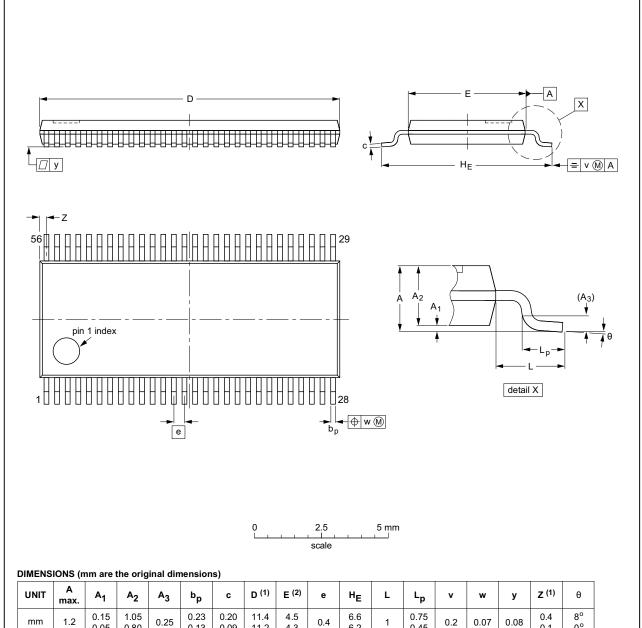
Fig 17. Package outline SOT364-1 (TSSOP56)

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#### TSSOP56: plastic thin shrink small outline package; 56 leads; body width 4.4 mm

SOT481-2



UNIT	A max.	A <sub>1</sub>	A <sub>2</sub>	A <sub>3</sub>	bp	С	D (1)	E (2)	е	HE	L	Lp	v	w	у	Z <sup>(1)</sup>	θ
mm	1.2	0.15 0.05	1.05 0.80	0.25	0.23 0.13	0.20 0.09	11.4 11.2	4.5 4.3	0.4	6.6 6.2	1	0.75 0.45	0.2	0.07	0.08	0.4 0.1	8° 0°

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT481-2		MO-194				01-11-24

Fig 18. Package outline SOT481-2 (TSSOP56)

74CBTLV16211

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### 13. Abbreviations

#### Table 12. Abbreviations

Acronym	Description
CDM	Charged Device Model
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model

## 14. Revision history

#### Table 13. Revision history

	,			
Document ID	Release date	Data sheet status	Change notice	Supersedes
74CBTLV16211 v.7	20161109	Product data sheet	-	74CBTLV16211 v.6
Modifications:	Section 11.1	and Section 11.2 added.	<u>'</u>	'
74CBTLV16211 v.6	20111215	Product data sheet	-	74CBTLV16211 v.5
Modifications:	Legal pages	updated.	,	•
74CBTLV16211 v.5	20101230	Product data sheet	-	74CBTLV16211 v.4
74CBTLV16211 v.4	20100816	Product data sheet	-	74CBTLV16211 v.3
74CBTLV16211 v.3	20100112	Product data sheet	-	74CBTLV16211 v.2
74CBTLV16211 v.2	20090826	Product data sheet	-	74CBTLV16211 v.1
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### 15. Legal information

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Document status[1][2]	Product status[3]	Definition
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- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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